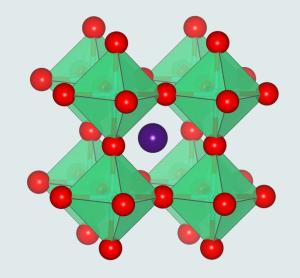
https://github.com/rsc-solid-data/data_diffn_crystals

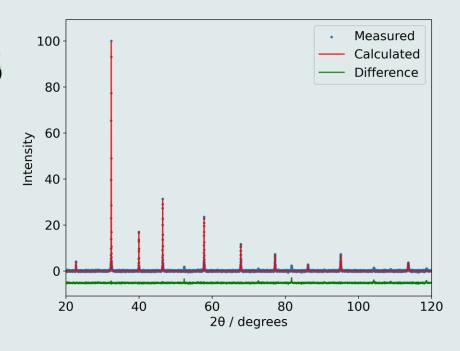
Data and Models of Solid State Structures



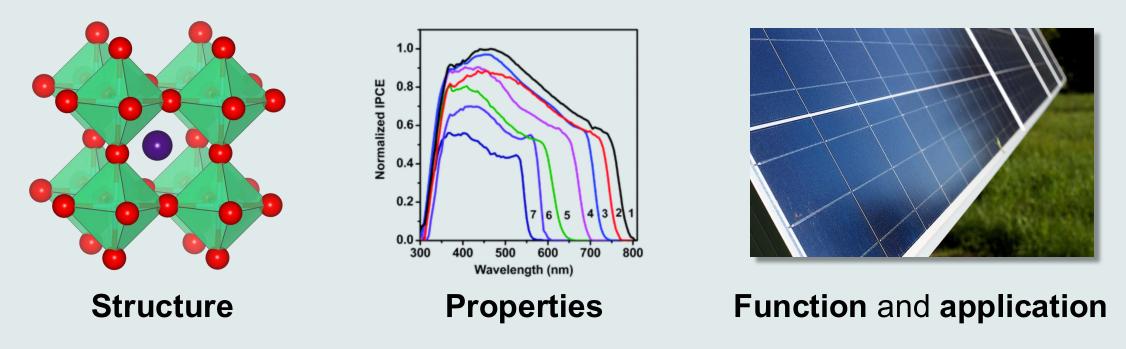






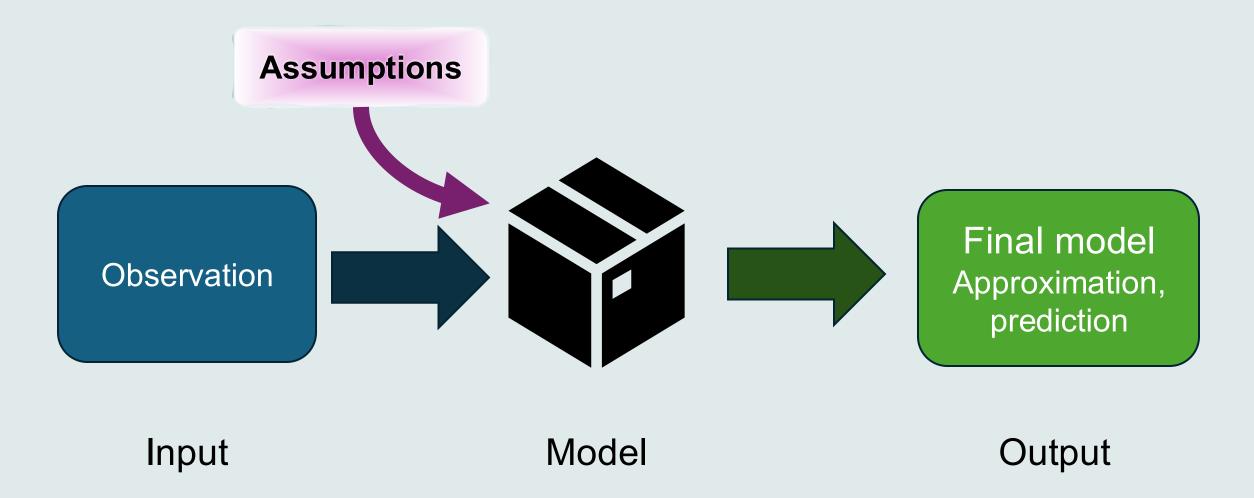


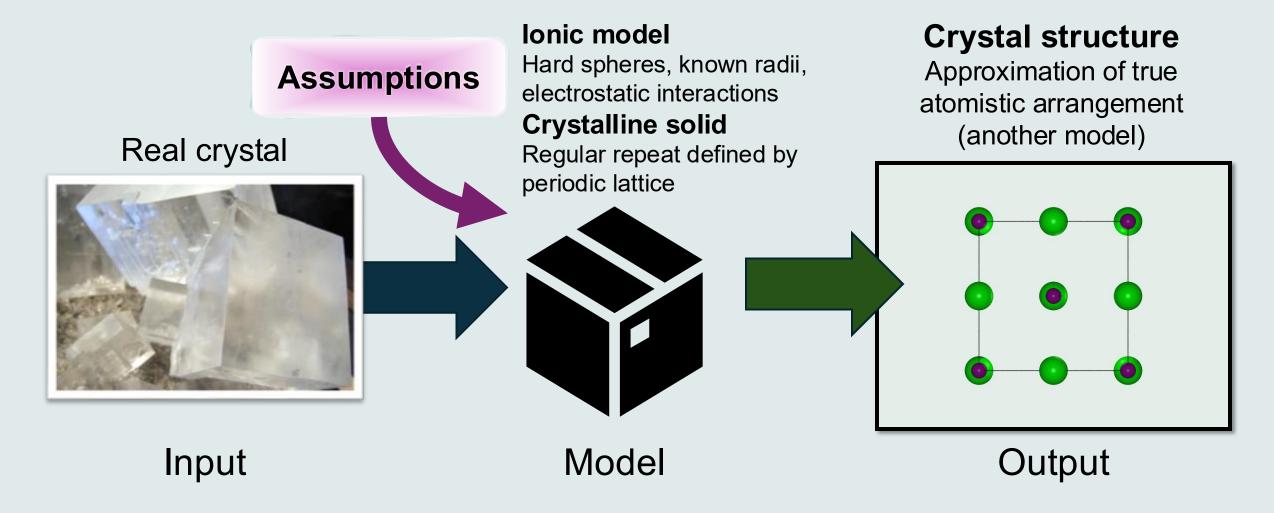
Structure: Foundation of materials "design"

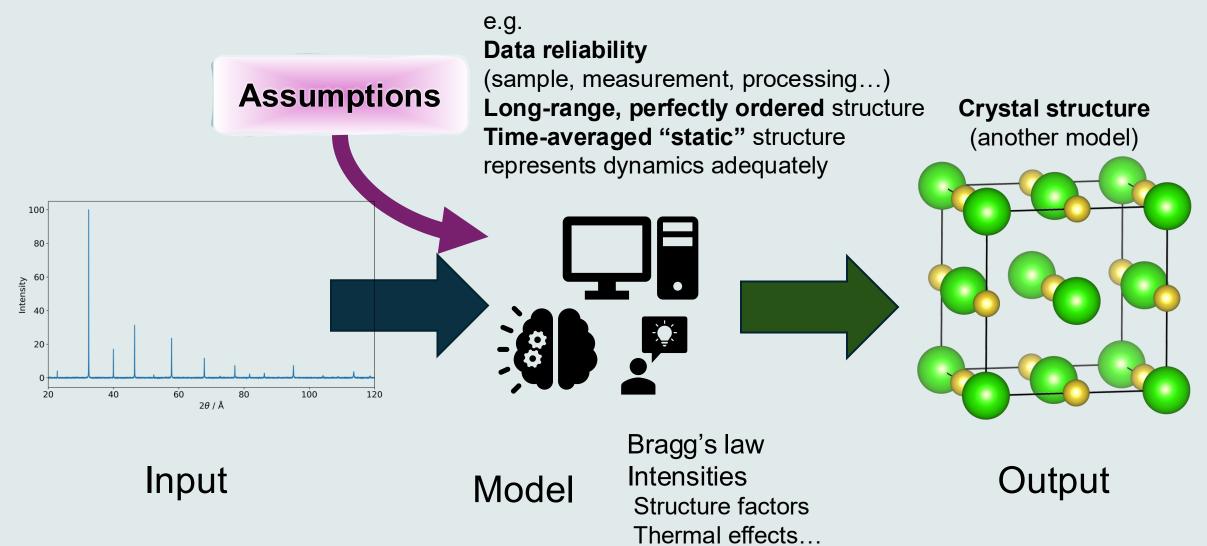


- Solid state structure underpins function in materials, from conductivity to colour.
- Representations of solid-state structure are **models**, not direct observations.
- Accurate, truly representative structural models are vital
 - → Valid structure-property relationships

S. A. Kulkarni et al., J. Mater. Chem. A, 2014, 2, 9221.







Assumptions

Measurable data

- XRD
- IR
- Raman

Properties

- Optical
- Porosity
- Guest affinity
- Conduction

Output

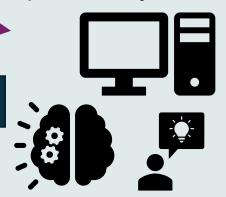
e.g.

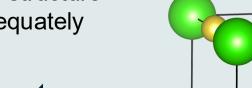
Model reliability

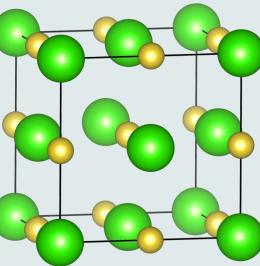
(physically realistic, precision on refined parameters)

Long-range, perfectly ordered structure

Time-averaged "static" structure represents dynamics adequately







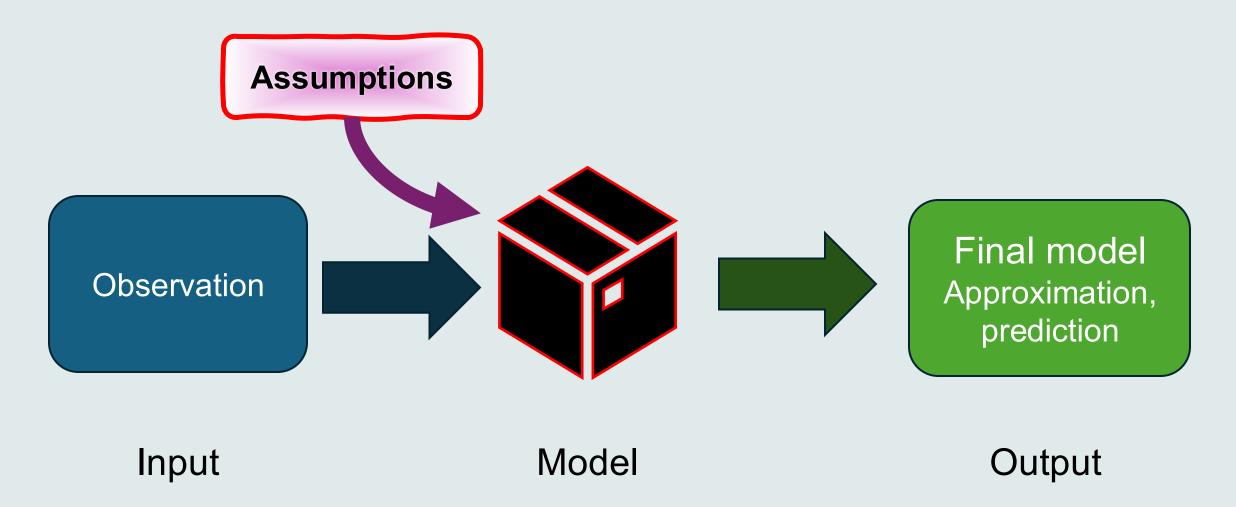
Crystal structure

(another model)

Model

Bragg's law
Intensities
Structure factors
Thermal effects...

Input



"All models are wrong, but some are useful"

- George E. P. Box

2.3 Parsimony

Since all models are wrong the scientist cannot obtain

a "correct" one by excessive elaboration

In applying mathematics to subjects such as physics or statistics we make tentative assumptions about the real world which we know are false but which we believe may be useful nonetheless.

2.4 Worrying Selectively

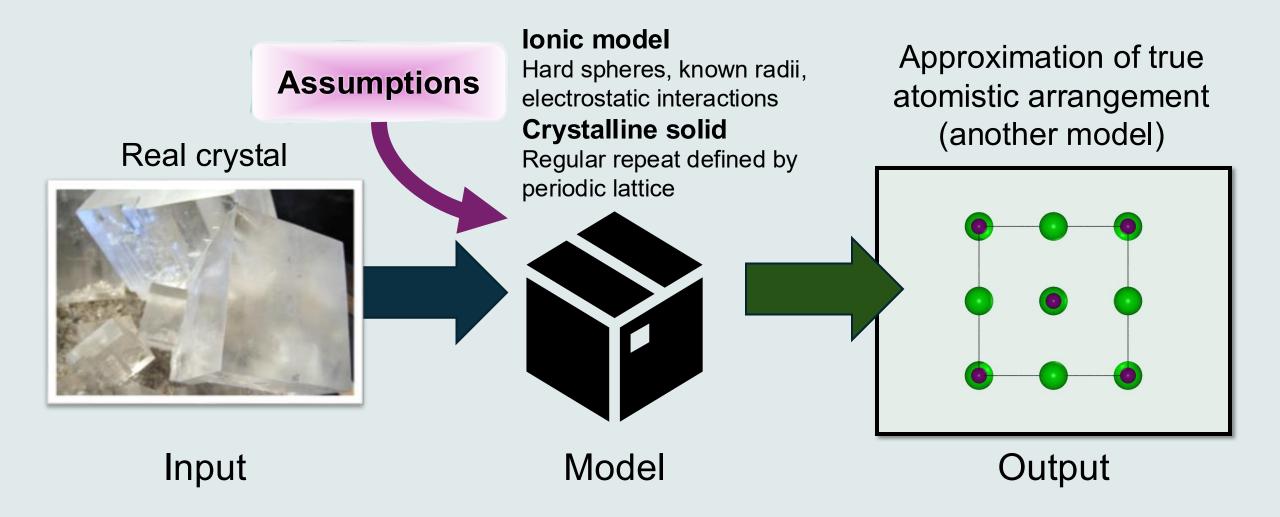
Since all models are wrong the scientist must be alert to what is importantly wrong. It is inappropriate to be concerned about mice when there are tigers abroad.

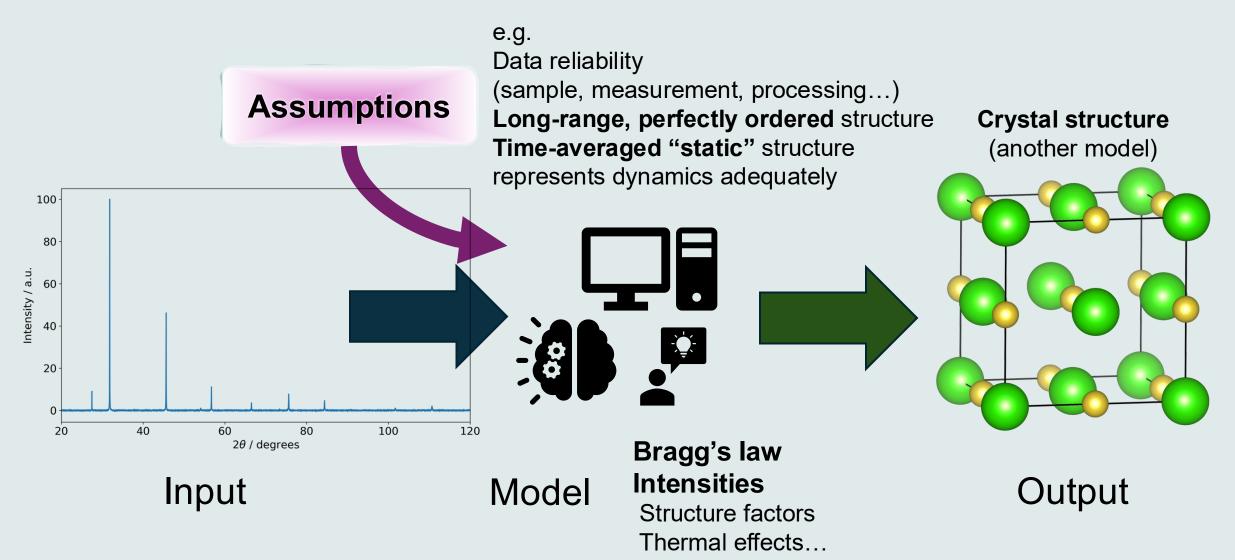
https://en.wikipedia.org/wiki/All_models_are_wrong

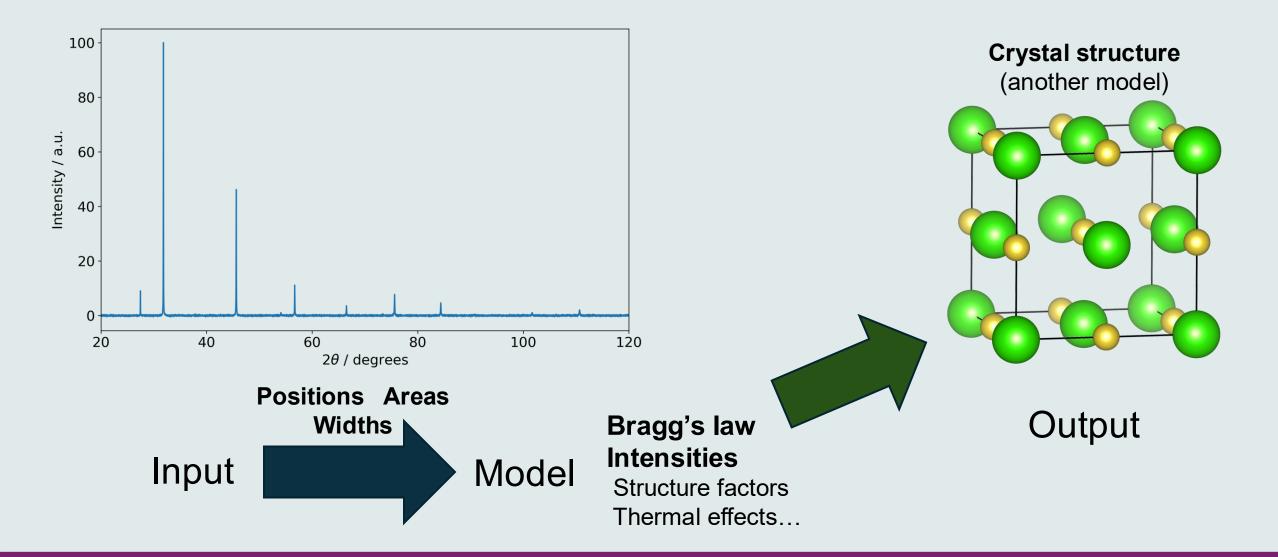
G.E.P. Box, Journal of the American Statistical Association, Vol. 71, No. 356. (1976), pp. 791-799.

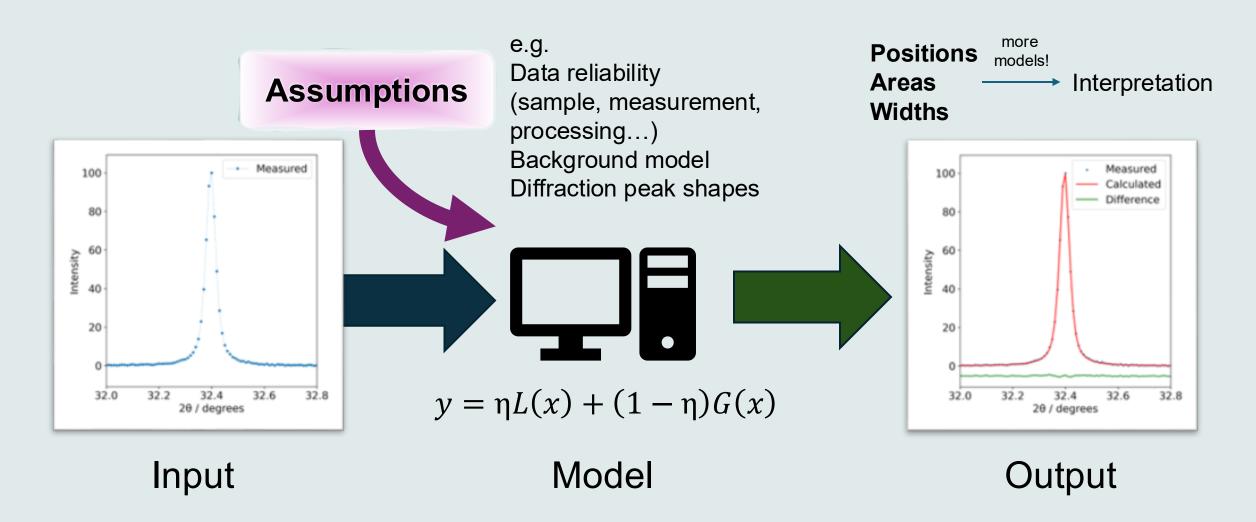
Crystallography

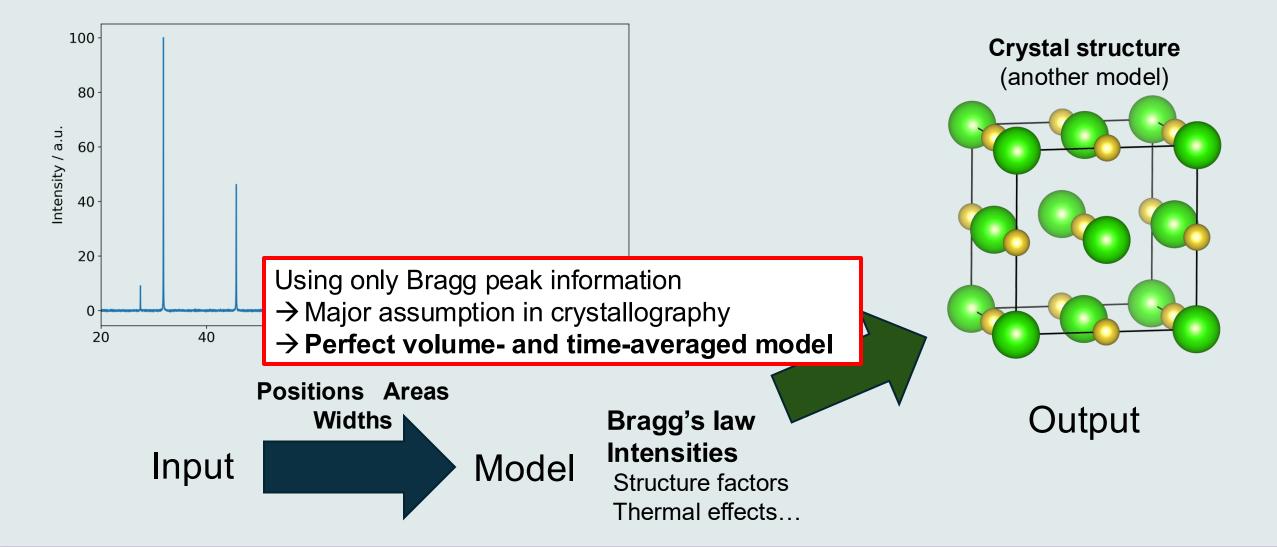
Modelling crystals











Modelling the diffraction pattern

Bragg's law

$$\lambda = 2d_{hkl} \sin \theta_{hkl}$$
 reflection (hkl) positions

Scattering intensities

$$F_{hkl} = \sum_{j} f_{j} \exp 2\pi i (hx_{j} + ky_{j} + lz_{j})$$

 f_j is the scattering factor for atom j at the position (x_j, y_j, z_j) in the unit cell. For X-rays, it is related to the atomic number of j

$$I_{hkl} \propto |F_{hkl}|^2$$

Analysis of diffraction intensities

$$\rho_{xyz} = \frac{1}{V} \sum_{hkl} F_{O,hkl} \exp[-2\pi i(hx + ky + lz)]$$

$$= \frac{1}{V} \sum_{hkl} |F_{O,hkl}| \exp(i\Phi_{hkl}) \exp[-2\pi i(hx + ky + lz)]$$

. . .

$$= \frac{1}{V} \sum_{l=1}^{N} |F_{O,hkl}| \cos[2\pi (hx + ky + lz) - \Phi_{hkl}]$$

Reciprocal space: diffraction

$$F_{hkl} = \sum_{j} f_{j} \exp 2\pi i (hx_{j} + ky_{j} + lz_{j})$$



Fourier transform FT Inverse Fourier transform (FT)-1

$$\rho_{hkl} = \frac{1}{V} \sum_{hkl} |F_{O,hkl}| \cos[2\pi(hx + ky + lz) - \Phi_{hkl}]$$

Real space: crystal structure

Structure determination from PXRD

- Reliable intensities I_{hkl} from PXRD profiles can be challenging
 - Reflections often overlap and cannot be fully resolved
- If an approximate model of the crystal structure is available:
 - Calculate diffraction pattern for the model
 - Use least square refinement (minimisation) to vary the model parameters to produce a good match for the experimental data
- Optimisation of a structural model to fit the whole experimental powder profile:

Rietveld refinement

Model refinement

Initial structural model

- Unit cell and symmetry (crystal system, lattice centring, space group)

 - $a, b, c, \alpha, \beta, \gamma \leftrightarrow \text{Positions of reflections}$
 - P, I, F

- → Systematic absences
- Atomic contents and positions
 - For each atom: species (f_i)

→ Intensities

position x, y, z

atomic displacement b

Experimental model

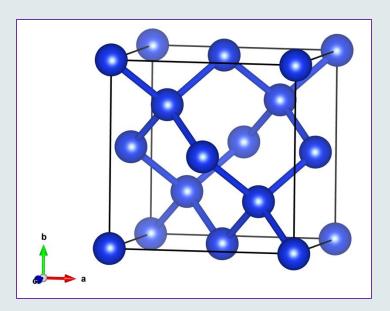
- Diffractometer
- Data collection
 - ← Intensities

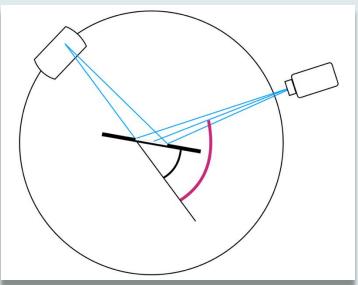
→ Peak positions

Sample model

- Crystal size
- Sample format

→ peak shapes





Least squares minimisation

$$S_y = \chi^2 = \sum_i w_i (y_{o,i} - y_{c,i})^2$$

Usual weighting scheme for PXRD: $w_i = \frac{1}{\sigma_{o,i}^2} = \frac{1}{y_{o,i}}$ σ is standard uncertainty on the measured data point

where
$$y_{c,i} = s \sum_{K} L_{K} |F_{K}|^{2} \phi(2\theta_{i} - 2\theta_{K}) P_{K} A_{i} + y_{b,i}$$

S – goodness of fit

i – data points in profile

w – weight

 y_o – observed intensity

 y_c – calculated intensity

 y_b – background intensity

F – structure factor

K - hkI

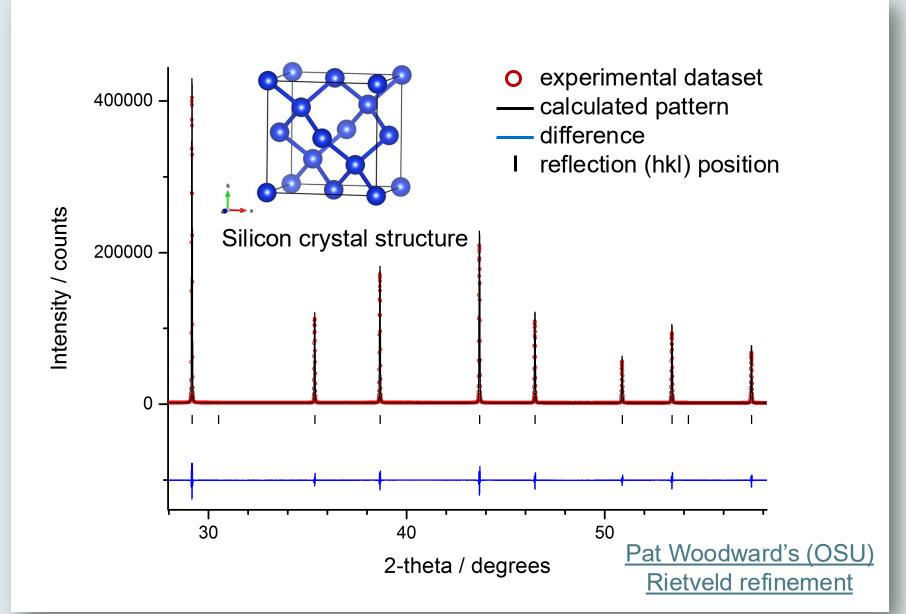
s – scale factor

L – Lorentz polarisation factor

 $\varphi(2\theta_i - 2\theta_K)$ – peak shape function

P – preferred orientation function

A – absorption (function)





Accessing structural data

- Crystal structures
 - BYO determined from diffraction
 - ICSD
 - CSD
 - <u>COD</u>
 - PDB, minerals, incommensurate
 - Materials Project
 - PCOD
 - OQMD

- Diffraction data
 - <u>ICDD</u> (PDF-4/5+, etc.)
 - P2D2 (from PCOD)
 - BYO
 - collect data
 - from crystal structures

https://github.com/rsc-solid-data/data_diffn_crystals

Comparing XRD profiles

- Be aware of where the cifs are from
 - Experimental conditions
 - Comparability of molecular simulations
- Be aware of where the experimental data is from
 - Experimental conditions
 - Sample compositions (guest inclusion, compositional variation)
 - Sample effects (size, preferred orientation, absorption, phase purity)
 - Instrumental considerations (broadening, Lp, optics)
 - Structural effects (order/disorder, symmetry, phase transitions)

Comparing XRD profiles

- Try the unit cell and space group
 - Structureless refinement no atoms, arbitrary intensities
 - Le Bail or Pawley
- Try a refinement
 - Rietveld refinement is local minimisation
 - Need a good starting model

Some extra resources

Fundamentals of Powder Diffraction and Structural Characterization of Materials, Springer US, Boston, MA, 2009.

B. H. Toby, *R* factors in Rietveld analysis: How good is good enough?, *Powder Diffr.*, 2006, **21**, 67–70.

L. B. McCusker, R. B. Von Dreele, D. E. Cox, D. Louër and P. Scardi, Rietveld refinement guidelines, *J Appl Cryst*, 1999, **32**, 36–50.

J. H. O'Donnell, R. B. Von Dreele, M. K. Y. Chan and B. H. Toby, A scripting interface for GSAS-II, *J Appl Cryst*, 2018, **51**, 1244–1250.